TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

## TLP281,TLP281-4

# PROGRAMMABLE CONTROLLERS AC/DC-INPUT MODULE PC CARD MODEM(PCMCIA)

TLP281 and TLP281-4 is a very small and thin coupler, suitable for surface mount assembly in applications such as PCMCIA Fax modem, programmable controllers.

TLP281 and TLP281-4 consist of photo transistor, optically coupled to a gallium arsenide infrared emitting diode.

Collector-Emitter Voltage : 80 V (MIN)
 Current Transfer Ratio : 50% (MIN)
 Rank GB : 100% (MIN)
 Isolation Voltage : 2500 Vrms (MIN)

• UL Recognized : UL1577 , File No. E67349

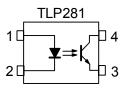
BSI Approved : BS EN 60065: 2002,

: BS EN 60950-1: 2002 Certificate No. 8143, 8144

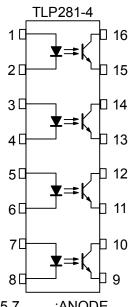
# Unit in mm TLP281 1 2 2.6 ± 0.25 0.4 ± 0.1 1.27 ± 0.2 TOSHIBA — Unit in mm TLP281

Weight: 0.05 g

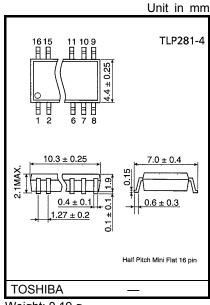
### Pin Configuration (top view)



1:ANODE 2:CATHODE 3:EMITTER 4:COLLECTOR



1,3,5,7 :ANODE 2,4,6,8 :CATHODE 9,11,13,15 :EMITTER 10,12,14,16 :COLLECTOR



Weight: 0.19 g

TYPE	Classi- Fication(*1)	(I <sub>C</sub>	fer Ration (%) / I <sub>F</sub> ) = 5 V, Ta = 25°C	Marking of Classification		
		Min	Max			
	Blank	50	600	Blank ,Y <sup>®</sup> ,YE,G,G <sup>®</sup> ,GR,B,BL,GB		
	Rank Y	50	150	YE		
	Rank GR	100	300	GR		
	Rank BL	200	600	BL		
TLP281	Rank GB	100	600	GB		
	Rank YH	75	150	Y=		
	Rank GRL	100	200	G		
	Rank GRH	150	300	G <sup>®</sup>		
	Rank BLL	200	400	В		
TLP281-4	Blank	50	600	Blank , GB		
1LF 201-4	Rank GB	100	600	GB		

<sup>\*1:</sup> Ex. rank GB: TLP281 (GB)

(Note): Application type name for certification test, please use standard product type name, i.e. TLP281 (GB): TLP281-1, TLP281-4 (GB): TLP281-4

### Absolute Maximum Ratings (Ta = 25°C)

TOSHIBA

CHARACTERISTIC		SYMBOL	RAT	UNIT		
		STIMBOL	TLP281	TLP281-4	OIVII	
Forward Current		lF	50		mA	
	Forward Current Derating	ΔI <sub>F</sub> /°C	−0.7 (Ta≥53°C)	−0.5 (Ta≥25°C)	mA /°C	
ED	Pulse Forward Current	I <sub>FP</sub>	-	Α		
	Reverse Voltage	V <sub>R</sub>	ţ	5		
	Junction Temperature	Tj	12	25	°C	
	Collector-Emitter Voltage	V <sub>CEO</sub>	8	0	V	
	Emitter-Collector Voltage	V <sub>ECO</sub>	-	V		
N	Collector Current	IC	50		mA	
DETECTOR	Collector Power Dissipation (1 Circuit)	P <sub>C</sub>	150	100	mW	
	Collector Power Dissipation Derating(Ta≥25°C) (1 Circuit)	ΔP <sub>C</sub> /°C	-1.5	-1.0	mW /°C	
	Junction Temperature	Tj	125		°C	
Оре	erating Temperature Range	T <sub>opr</sub>	-55~100		°C	
Storage Temperature Range		T <sub>stg</sub>	-55~125		°C	
Lead Soldering Temperature		T <sub>sol</sub>	260 (10s)		°C	
Total Package Power Dissipation (1 Circuit)		PT	200	170	mW	
	al Package Power Dissipation ating (Ta≥25°C) (1 Circuit)	ΔP <sub>T</sub> /°C	-2.0	-1.7	mW /°C	
Isol	ation Voltage (Note1)	$BV_S$	2500(AC,1mi	in,R.H.≤60%)	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note1) Device considered a two terminal device : LED side pins shorted together and DETECTOR side pins shorted together.

### Individual Electrical Characteristics (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μΑ
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	_	pF
	Collector-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> = 0.5 mA	80	_		<b>V</b>
TOR	Emitter-Collector Breakdown Voltage	V <sub>(BR)</sub> ECO	I <sub>E</sub> = 0.1 mA	7	_	_	V
DETECTOR	Collector Dark Current (Note2)	I <sub>CEO</sub>	V <sub>CE</sub> = 48 V, Ambient Light Below (100 &x)	_	0.01 (2)	0.1 (10)	μΑ
			V <sub>CE</sub> = 48 V, Ta = 85°C Ambient Light Below (100 tx)	_	2 (4)	50 (50)	μΑ
	Capacitance (Collector to Emitter)	C <sub>CE</sub>	V = 0, f = 1 MHz	_	10	_	pF

(Note 2) Because of the construction,leak current might be increased by ambient light.

Please use photocoupler with less ambient light.

### Coupled Electrical Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I <sub>C</sub> / I <sub>F</sub>	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V	50	_	600	- %
Current Transfer Natio		Rank GB	100	_	600	
Saturated CTR	I <sub>C</sub> / I <sub>F (sat)</sub>	IF = 1 mA, VCE = 0.4 V		60	_	%
Saluraled CTK		Rank GB	30	_	_	/0
Collector-Emitter		I <sub>C</sub> = 2.4 mA, I <sub>F</sub> = 8 mA	_	_	0.4	
Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 0.2 mA, I <sub>F</sub> = 1 mA	_	0.2	_	٧
Saturation voltage		Rank GB	_	_	0.4	
Off-State Collector Current	I <sub>C (off)</sub>	V <sub>F</sub> = 0.7 V, V <sub>CE</sub> = 48 V		_	10	μA

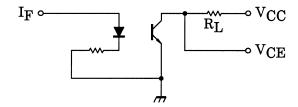
### Isolation Characteristics (Ta = 25°C)

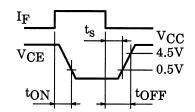
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	CS	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation Resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H.≤60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
	BVS	AC , 1 minute	2500	_	_	Vrms
Isolation Voltage		AC , 1 second,in OIL	_	5000	_	VIIIIS
		DC , 1 minute, in OIL	_	5000	_	Vdc

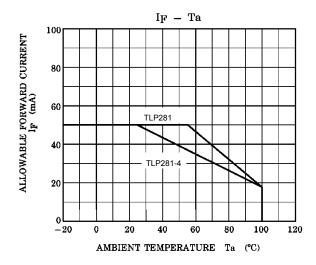
### **Switching Characteristics (Ta = 25°C)**

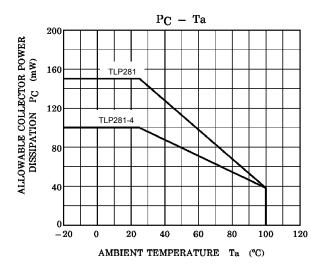
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Rise Time	t <sub>r</sub>		_	2	_	ue
Fall Time	t <sub>f</sub>	V <sub>CC</sub> = 10 V, I <sub>C</sub> = 2 mA	_	3	_	
Turn-On Time	t <sub>on</sub>	$R_L = 100\Omega$	_	3	_	μs
Turn-Off Time	t <sub>off</sub>		_	3	_	
Turn-On Time	t <sub>ON</sub>		_	2	_	
Storage Time	ts	$R_L$ = 1.9 kΩ (Fig.1) $V_{CC}$ = 5 V, $I_F$ = 16 mA	_	25	_	μs
Turn-Off Time	toff		_	40	_	

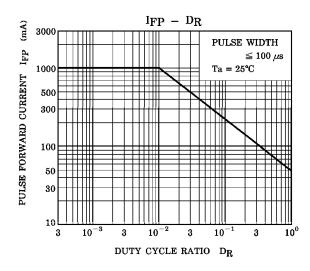
(Fig.1)SWITCHING TIME TEST CIRCUIT

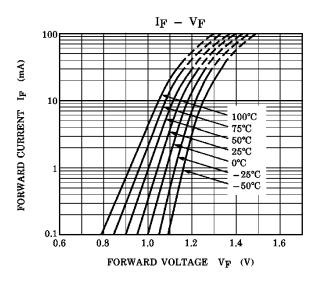


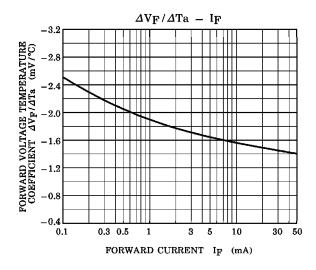


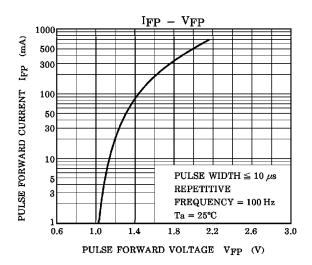


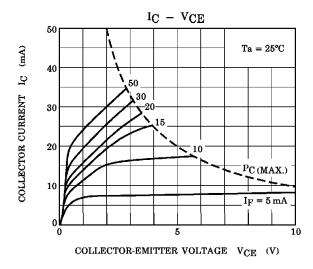


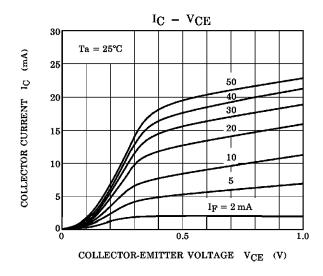


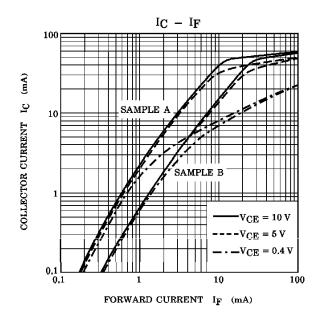


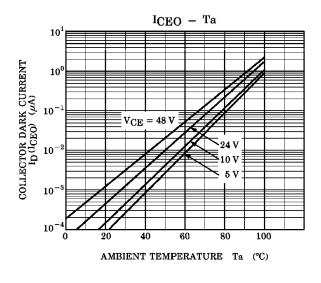


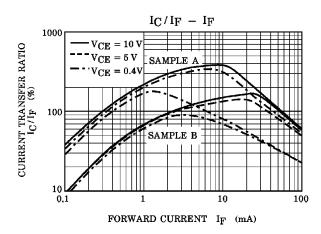




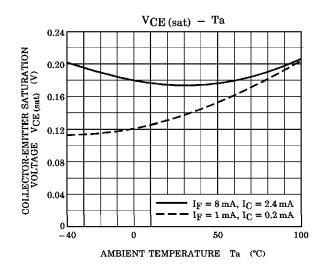


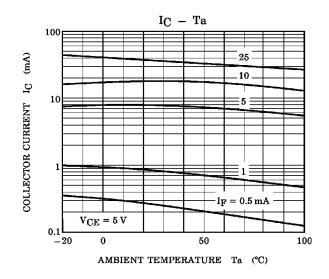


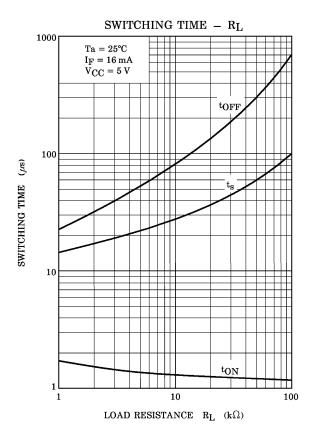


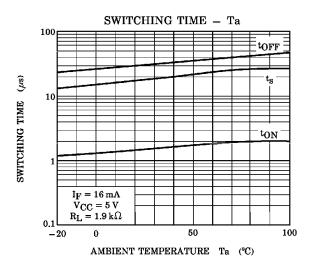


6 2007-10-01









### **RESTRICTIONS ON PRODUCT USE**

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No
  responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
  may result from its use. No license is granted by implication or otherwise under any patents or other rights of
  TOSHIBA or the third parties.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.
- Please contact your sales representative for product-by-product details in this document regarding RoHS
  compatibility. Please use these products in this document in compliance with all applicable laws and regulations
  that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
  occurring as a result of noncompliance with applicable laws and regulations.